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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	I ² C, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, LVD, POR, PWM, WDT
Number of I/O	54
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 16x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mkl14z32vlh4

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



Ordering Information

Part Number	Mer	nory	Maximum number of I\O's
	Flash (KB)	SRAM (KB)	
MKL14Z32VFM4	32	4	28
MKL14Z64VFM4	64	8	28
MKL14Z32VFT4	32	4	40
MKL14Z64VFT4	64	8	40
MKL14Z32VLH4	32	4	54
MKL14Z64VLH4	64	8	54
MKL14Z32VLK4	32	4	70
MKL14Z64VLK4	64	8	70

Related Resources

Туре	Description	Resource
Selector Guide	The Freescale Solution Advisor is a web-based tool that features interactive application wizards and a dynamic product selector.	Solution Advisor
Product Brief	The Product Brief contains concise overview/summary information to enable quick evaluation of a device for design suitability.	KL1 Family Product Brief ¹
Reference Manual	The Reference Manual contains a comprehensive description of the structure and function (operation) of a device.	KL14P80M48SF0RM ¹
Data Sheet	The Data Sheet includes electrical characteristics and signal connections.	KL14P80M48SF0 ¹
Chip Errata	The chip mask set Errata provides additional or corrective information for a particular device mask set.	KINETIS_L_xN97F ²
Package	Package dimensions are provided in package drawings.	QFN 32-pin: 98ASA00473D ¹
drawing		QFN 48-pin: 98ASA00466D ¹
		LQFP 64-pin: 98ASS23234W ¹
		LQFP 80-pin: 98ASS23174W ¹

1. To find the associated resource, go to http://www.freescale.com and perform a search using this term.

To find the associated resource, go to http://www.freescale.com and perform a search using this term with the "x" replaced by the revision of the device you are using.

Figure 1 shows the functional modules in the chip.



Symbol	Description	Min.	Max.	Unit	Notes
V _{DD}	Supply voltage	1.71	3.6	V	
V _{DDA}	Analog supply voltage	1.71	3.6	V	—
$V_{DD} - V_{DDA}$	V _{DD} -to-V _{DDA} differential voltage	-0.1	0.1	V	—
$V_{SS} - V_{SSA}$	V _{SS} -to-V _{SSA} differential voltage	-0.1	0.1	V	—
V _{IH}	Input high voltage				—
	• $2.7 \text{ V} \le \text{V}_{\text{DD}} \le 3.6 \text{ V}$	$0.7 \times V_{DD}$	—	V	
	• $1.7 \text{ V} \le \text{V}_{\text{DD}} \le 2.7 \text{ V}$	$0.75 \times V_{DD}$	_	V	
V _{IL}	Input low voltage				_
	• $2.7 \text{ V} \le \text{V}_{\text{DD}} \le 3.6 \text{ V}$	_	$0.35 \times V_{DD}$	V	
	• $1.7 \text{ V} \le \text{V}_{\text{DD}} \le 2.7 \text{ V}$		$0.3 \times V_{DD}$	V	
V _{HYS}	Input hysteresis	$0.06 \times V_{DD}$	_	V	_
I _{ICIO}	IO pin negative DC injection current—single pin • V _{IN} < V _{SS} –0.3V	-3	_	mA	1
I _{ICcont}	Contiguous pin DC injection current —regional limit, includes sum of negative injection currents of 16 contiguous pins • Negative current injection	-25		mA	_
V _{ODPU}	Open drain pullup voltage level	V _{DD}	V _{DD}	V	2
V _{RAM}	V _{DD} voltage required to retain RAM	1.2	_	V	—

2.2.1 Voltage and current operating requirements Table 5. Voltage and current operating requirements

2. Open drain outputs must be pulled to V_{DD} .

2.2.2 LVD and POR operating requirements T

able 6.	V _{DD} supply LVD and PO	R operating requirements
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Symbol	Description	Min.	Тур.	Max.	Unit	Notes
V _{POR}	Falling V _{DD} POR detect voltage	0.8	1.1	1.5	V	—
V _{LVDH}	Falling low-voltage detect threshold — high range (LVDV = 01)	2.48	2.56	2.64	V	—
	Low-voltage warning thresholds — high range					1

Table continues on the next page ...

^{1.} All I/O pins are internally clamped to V_{SS} through a ESD protection diode. There is no diode connection to V_{DD} . If V_{IN} greater than V_{IO_MIN} (= V_{SS}-0.3 V) is observed, then there is no need to provide current limiting resistors at the pads. If this limit cannot be observed then a current limiting resistor is required. The negative DC injection current limiting resistor is calculated as $R = (V_{IO MIN} - V_{IN})/|I_{ICIO}|$.



Symbol	Description	Min.	Тур.	Max.	Unit	Notes
V _{LVW1H}	 Level 1 falling (LVWV = 00) 	2.62	2.70	2.78	V	
V _{LVW2H}	 Level 2 falling (LVWV = 01) 	2.72	2.80	2.88	V	
V _{LVW3H}	 Level 3 falling (LVWV = 10) 	2.82	2.90	2.98	V	
V _{LVW4H}	• Level 4 falling (LVWV = 11)	2.92	3.00	3.08	v	
V _{HYSH}	Low-voltage inhibit reset/recover hysteresis — high range		±60		mV	_
V _{LVDL}	Falling low-voltage detect threshold — low range (LVDV=00)	1.54	1.60	1.66	V	_
	Low-voltage warning thresholds — low range					1
V _{LVW1L}	• Level 1 falling (LVWV = 00)	1.74	1.80	1.86	v	
V _{LVW2L}	 Level 2 falling (LVWV = 01) 	1.84	1.90	1.96	v	
V _{LVW3L}	 Level 3 falling (LVWV = 10) 	1.94	2.00	2.06	v	
V _{LVW4L}	• Level 4 falling (LVWV = 11)	2.04	2.10	2.16	v	
V _{HYSL}	Low-voltage inhibit reset/recover hysteresis — low range	_	±40	_	mV	_
V _{BG}	Bandgap voltage reference	0.97	1.00	1.03	V	—
t _{LPO}	Internal low power oscillator period — factory trimmed	900	1000	1100	μs	—

Table 6. V_{DD} supply LVD and POR operating requirements (continued)

1. Rising thresholds are falling threshold + hysteresis voltage

2.2.3 Voltage and current operating behaviors

Table 7. Voltage and current operating behaviors

Symbol	Description	Min.	Max.	Unit	Notes
V _{OH}	Output high voltage — Normal drive pad (except RESET)				1, 2
	 2.7 V ≤ V_{DD} ≤ 3.6 V, I_{OH} = −5 mA 	V _{DD} – 0.5	—	V	
	• $1.71 \text{ V} \le \text{V}_{\text{DD}} \le 2.7 \text{ V}, \text{ I}_{\text{OH}} = -1.5 \text{ mA}$	V _{DD} – 0.5	_	V	
V _{OH}	Output high voltage — High drive pad (except RESET)				1, 2
	 2.7 V ≤ V_{DD} ≤ 3.6 V, I_{OH} = −18 mA 	V _{DD} – 0.5	—	V	
	• $1.71 \text{ V} \le \text{V}_{\text{DD}} \le 2.7 \text{ V}, \text{ I}_{\text{OH}} = -6 \text{ mA}$	V _{DD} – 0.5	_	V	
I _{OHT}	Output high current total for all ports	—	100	mA	_
V _{OL}	Output low voltage — Normal drive pad				1
	• 2.7 V \leq V _{DD} \leq 3.6 V, I _{OL} = 5 mA	_	0.5	v	
	• $1.71 \text{ V} \le \text{V}_{\text{DD}} \le 2.7 \text{ V}, \text{ I}_{\text{OL}} = 1.5 \text{ mA}$	_	0.5	V	

Table continues on the next page...





Figure 4. VLPR mode current vs. core frequency

2.2.6 EMC radiated emissions operating behaviors

 Table 11. EMC radiated emissions operating behaviors for 64-pin LQFP package

Symbol	Description	Frequency band (MHz)	Тур.	Unit	Notes
V _{RE1}	Radiated emissions voltage, band 1	0.15–50	13	dBµV	1, 2
V _{RE2}	Radiated emissions voltage, band 2	50–150	15	dBµV	
V _{RE3}	Radiated emissions voltage, band 3	150–500	12	dBµV	
V _{RE4}	Radiated emissions voltage, band 4	500–1000	7	dBµV	
V _{RE_IEC}	IEC level	0.15–1000	М	_	2, 3

 Determined according to IEC Standard 61967-1, Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions and IEC Standard 61967-2, Integrated Circuits -Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method. Measurements were made while the microcontroller was running basic



2.4.2 Thermal attributes

Table 16. Thern	nal attributes
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Board type	Symbol	Description	80 LQFP	64 LQFP	48 QFN	32 QFN	Unit	Notes
Single-layer (1S)	R _{θJA}	Thermal resistance, junction to ambient (natural convection)	70	71	84	92	°C/W	1
Four-layer (2s2p)	R _{θJA}	Thermal resistance, junction to ambient (natural convection)	53	52	28	33	°C/W	
Single-layer (1S)	R _{θJMA}	Thermal resistance, junction to ambient (200 ft./min. air speed)	_	59	69	75	°C/W	
Four-layer (2s2p)	R _{θJMA}	Thermal resistance, junction to ambient (200 ft./min. air speed)	_	46	22	27	°C/W	
_	R _{θJB}	Thermal resistance, junction to board	34	34	10	12	°C/W	2
	R _{θJC}	Thermal resistance, junction to case	15	20	2.0	1.8	°C/W	3
_	Ψ_{JT}	Thermal characterization parameter, junction to package top outside center (natural convection)	0.6	5	5.0	8	°C/W	4

1. Determined according to JEDEC Standard JESD51-2, Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air), or EIA/JEDEC Standard JESD51-6, Integrated Circuit Thermal Test Method Environmental Conditions—Forced Convection (Moving Air).

- 2. Determined according to JEDEC Standard JESD51-8, Integrated Circuit Thermal Test Method Environmental Conditions—Junction-to-Board.
- 3. Determined according to Method 1012.1 of MIL-STD 883, *Test Method Standard, Microcircuits*, with the cold plate temperature used for the case temperature. The value includes the thermal resistance of the interface material between the top of the package and the cold plate.
- 4. Determined according to JEDEC Standard JESD51-2, Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air).

3 Peripheral operating requirements and behaviors

3.1 Core modules



Peripheral operating requirements and behaviors



Figure 6. Serial wire data timing

3.2 System modules

There are no specifications necessary for the device's system modules.

3.3 Clock modules

3.3.1 MCG specifications

Table 18. MCG specifications

Symbol	Description	Min.	Тур.	Max.	Unit	Notes
f _{ints_ft}	Internal reference frequency (slow clock) — factory trimmed at nominal V_{DD} and 25 °C	_	32.768	—	kHz	
f _{ints_t}	Internal reference frequency (slow clock) — user trimmed	31.25	_	39.0625	kHz	
$\Delta_{fdco_res_t}$	Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using C3[SCTRIM] and C4[SCFTRIM]	—	± 0.3	± 0.6	%f _{dco}	1

Table continues on the next page...



Symbol	Description		Min.	Тур.	Max.	Unit	Notes	
Δf _{dco_t}	Total deviation of t frequency over vol	trimmed average DCO output Itage and temperature	—	+0.5/-0.7	± 3	%f _{dco}	1, 2	
∆f _{dco_t}	Total deviation of t frequency over fixe range of 0–70 °C	rimmed average DCO output ed voltage and temperature	_	± 0.4	± 1.5	%f _{dco}	1, 2	
f _{intf_ft}	Internal reference factory trimmed at	frequency (fast clock) — nominal V _{DD} and 25 °C		4	—	MHz		
∆f _{intf_ft}	Frequency deviation (fast clock) over te factory trimmed at	on of internal reference clock mperature and voltage — nominal V _{DD} and 25 °C	_	+1/-2	± 3	%f _{intf_ft}	2	
f _{intf_t}	Internal reference trimmed at nomina	frequency (fast clock) — user al V _{DD} and 25 °C	3		5	MHz		
f _{loc_low}	Loss of external cl RANGE = 00	ock minimum frequency —	(3/5) x f _{ints_t}		—	kHz		
f _{loc_high}	Loss of external cl RANGE = 01, 10,	ock minimum frequency — or 11	(16/5) x f _{ints_t}		—	kHz		
		FI	LL					
f _{fll_ref}	FLL reference free	luency range	31.25	_	39.0625	kHz		
f _{dco}	DCO output frequency range	Low range (DRS = 00) 640 × f _{fll ref}	20	20.97	25	MHz	3, 4	
		Mid range (DRS = 01) $1280 \times f_{fll_ref}$	40	41.94	48	MHz		
f _{dco_t_DMX3}	DCO output frequency	Low range (DRS = 00) 732 × f _{fll_ref}	_	23.99	_	MHz	5, 6	
		Mid range (DRS = 01) $1464 \times f_{fll_ref}$	_	47.97	_	MHz		
J _{cyc_fll}	FLL period jitter • f _{VCO} = 48 MI	Hz	_	180	—	ps	7	
t _{fll acquire}	FLL target frequen	ncy acquisition time	_	_	1	ms	8	
	-	P	LL					
f _{vco}	VCO operating fre	quency	48.0	_	100	MHz		
I _{pll}	PLL operating curr PLL at 96 M 2 MHz, VDI	rent Hz (f _{osc_hi_1} = 8 MHz, f _{pll_ref} = / multiplier = 48)	_	1060	_	μΑ	9	
I _{pll}	PLL operating curr PLL at 48 M 2 MHz, VDIV	rent Hz (f _{osc_hi_1} = 8 MHz, f _{pll_ref} = / multiplier = 24)	_	600	_	μΑ	9	
f _{pll_ref}	PLL reference free	quency range	2.0	_	4.0	MHz		
J _{cyc_pll}	PLL period jitter (F	RMS)					10	
	• f _{vco} = 48 MH	z	_	120	—	ps		
	• f _{vco} = 100 M	Hz	—	50	—	ps		

Table continues on the next page ...



Symbol	Description	Min.	Тур.	Max.	Unit	Notes
	• 24 MHz	_	1.5	—	mA	
	• 32 MHz					
I _{DDOSC}	Supply current — high gain mode (HGO=1)					1
	• 32 kHz	—	25	—	μA	
	• 4 MHz	—	400	_	μA	
	• 8 MHz (RANGE=01)	—	500	—	μA	
	• 16 MHz	—	2.5	—	mA	
	• 24 MHz	—	3	—	mA	
	• 32 MHz	—	4	—	mA	
C _x	EXTAL load capacitance		_	_		2, 3
Cy	XTAL load capacitance	_				2, 3
R _F	Feedback resistor — low-frequency, low-power mode (HGO=0)	_	_	_	MΩ	2, 4
	Feedback resistor — low-frequency, high-gain mode (HGO=1)	—	10	—	MΩ	
	Feedback resistor — high-frequency, low-power mode (HGO=0)	_	_	_	MΩ	
	Feedback resistor — high-frequency, high-gain mode (HGO=1)	_	1	_	MΩ	
R _S	Series resistor — low-frequency, low-power mode (HGO=0)	_	—	_	kΩ	
	Series resistor — low-frequency, high-gain mode (HGO=1)	—	200		kΩ	
	Series resistor — high-frequency, low-power mode (HGO=0)	_	_	_	kΩ	
	Series resistor — high-frequency, high-gain mode (HGO=1)					
		—	0	_	kΩ	
V _{pp} ⁵	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, low-power mode (HGO=0)	_	0.6	_	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, high-gain mode (HGO=1)	_	V _{DD}	_	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, low-power mode (HGO=0)		0.6		V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, high-gain mode (HGO=1)		V _{DD}		V	

Table 19.	Oscillator DC electrical s	pecifications ((continued)	1
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V_{DD}=3.3 V, Temperature =25 °C
 See crystal or resonator manufacturer's recommendation



Peripheral operating requirements and behaviors

- 3. C_x,C_y can be provided by using the integrated capacitors when the low frequency oscillator (RANGE = 00) is used. For all other cases external capacitors must be used.
- 4. When low power mode is selected, R_F is integrated and must not be attached externally.
- 5. The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other devices.

3.3.2.2 Oscillator frequency specifications Table 20. Oscillator frequency specifications

Symbol	Description	Min.	Тур.	Max.	Unit	Notes
f _{osc_lo}	Oscillator crystal or resonator frequency — low- frequency mode (MCG_C2[RANGE]=00)	32	_	40	kHz	
f _{osc_hi_1}	Oscillator crystal or resonator frequency — high- frequency mode (low range) (MCG_C2[RANGE]=01)	3	_	8	MHz	
f _{osc_hi_2}	Oscillator crystal or resonator frequency — high frequency mode (high range) (MCG_C2[RANGE]=1x)	8	_	32	MHz	
f _{ec_extal}	Input clock frequency (external clock mode)	_	—	48	MHz	1, 2
t _{dc_extal}	Input clock duty cycle (external clock mode)	40	50	60	%	
t _{cst}	Crystal startup time — 32 kHz low-frequency, low-power mode (HGO=0)	_	750	_	ms	3, 4
	Crystal startup time — 32 kHz low-frequency, high-gain mode (HGO=1)	—	250	_	ms	
	Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), low-power mode (HGO=0)	_	0.6	_	ms	
	Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), high-gain mode (HGO=1)	_	1	_	ms	

1. Other frequency limits may apply when external clock is being used as a reference for the FLL

- 2. When transitioning from FEI or FBI to FBE mode, restrict the frequency of the input clock so that, when it is divided by FRDIV, it remains within the limits of the DCO input clock frequency.
- 3. Proper PC board layout procedures must be followed to achieve specifications.
- Crystal startup time is defined as the time between the oscillator being enabled and the OSCINIT bit in the MCG_S
 register being set.

3.4 Memories and memory interfaces

3.4.1 Flash electrical specifications

This section describes the electrical characteristics of the flash memory module.



Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
R _{AS}	Analog source resistance (external)	12-bit modes f _{ADCK} < 4 MHz	_	_	5	kΩ	4
f _{ADCK}	ADC conversion clock frequency	≤ 12-bit mode	1.0	_	18.0	MHz	5
C _{rate}	ADC conversion rate	 ≤ 12-bit modes No ADC hardware averaging Continuous conversions enabled, subsequent conversion time 	20.000	_	818.330	Ksps	6

- 1. Typical values assume V_{DDA} = 3.0 V, Temp = 25 °C, f_{ADCK} = 1.0 MHz, unless otherwise stated. Typical values are for reference only, and are not tested in production.
- 2. DC potential difference.
- For packages without dedicated VREFH and VREFL pins, V_{REFH} is internally tied to V_{DDA}, and V_{REFL} is internally tied to V_{SSA}.
- 4. This resistance is external to MCU. To achieve the best results, the analog source resistance must be kept as low as possible. The results in this data sheet were derived from a system that had < 8 Ω analog source resistance. The R_{AS}/C_{AS} time constant should be kept to < 1 ns.</p>
- 5. To use the maximum ADC conversion clock frequency, CFG2[ADHSC] must be set and CFG1[ADLPC] must be clear.
- 6. For guidelines and examples of conversion rate calculation, download the ADC calculator tool.



Figure 7. ADC input impedance equivalency diagram



Peripheral operating requirements and behaviors

12-bit ADC electrical characteristics 3.6.1.2

Symbol	Description	Conditions ¹	Min.	Typ. ²	Max.	Unit	Notes
I _{DDA_ADC}	Supply current		0.215	_	1.7	mA	3
	ADC	• ADLPC = 1, ADHSC =	1.2	2.4	3.9	MHz	t _{ADACK} =
	asynchronous	0	2.4	4.0	6.1	MHz	1/f _{ADACK}
		 ADLPC = 1, ADHSC = 1 	3.0	5.2	7.3	MHz	
fadack		• ADLPC = 0, ADHSC = 0	4.4	6.2	9.5	MHz	
		• ADLPC = 0, ADHSC = 1					
	Sample Time	See Reference Manual chapte	r for sample	times			
TUE	Total unadjusted	12-bit modes	—	±4	±6.8	LSB ⁴	5
	error	12-bit modes	_	±1.4	±2.1		
DNL	Differential non- linearity	12-bit modes		±0.7	-1.1 to +1.9	LSB ⁴	5
		12-bit modes		±0.2	-0.3 to 0.5		
INL	Integral non- linearity	12-bit modes		±1.0	-2.7 to +1.9	LSB ⁴	5
		 <12-bit modes 	_	±0.5	–0.7 to +0.5		
E _{FS}	Full-scale error	12-bit modes	—	-4	-5.4	LSB ⁴	V _{ADIN} =
		 <12-bit modes 	—	-1.4	-1.8		V _{DDA} ⁵
EQ	Quantization error	12-bit modes	_	—	±0.5	LSB ⁴	
E _{IL}	Input leakage error			$I_{ln} \times R_{AS}$		mV	I _{In} = leakage current
							(refer to the MCU's voltage and current operating ratings)
	Temp sensor slope	Across the full temperature range of the device	1.55	1.62	1.69	mV/°C	6
V _{TEMP25}	Temp sensor voltage	25 °C	706	716	726	mV	6

Table 26. 12-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

1. All accuracy numbers assume the ADC is calibrated with $V_{REFH} = V_{DDA}$ 2. Typical values assume $V_{DDA} = 3.0 \text{ V}$, Temp = 25 °C, $f_{ADCK} = 2.0 \text{ MHz}$ unless otherwise stated. Typical values are for reference only and are not tested in production.





Figure 10. Typical hysteresis vs. Vin level (V_{DD} = 3.3 V, PMODE = 1)

3.7 Timers

See General switching specifications.

3.8 Communication interfaces

3.8.1 SPI switching specifications

The Serial Peripheral Interface (SPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following tables provide timing characteristics for classic SPI timing modes. See the SPI chapter of the chip's Reference Manual for information about the modified transfer formats used for communicating with slower peripheral devices.

All timing is shown with respect to $20\% V_{DD}$ and $80\% V_{DD}$ thresholds, unless noted, as well as input signal transitions of 3 ns and a 30 pF maximum load on all SPI pins.

Num.	Symbol	Description	Min.	Max.	Unit	Note
1	f _{op}	Frequency of operation	f _{periph} /2048	f _{periph} /2	Hz	1

Table 28. SPI master mode timing on slew rate disabled pads

Table continues on the next page...





3.8.3 UART

See General switching specifications.

4 Dimensions

4.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to **freescale.com** and perform a keyword search for the drawing's document number:

If you want the drawing for this package	Then use this document number
32-pin QFN	98ASA00473D
48-pin QFN	98ASA00466D
64-pin LQFP	98ASS23234W
80-pin LQFP	98ASS23174W

5 Pinout

5.1 KL14 Signal Multiplexing and Pin Assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

80 LQFP	64 LQFP	48 QFN	32 QFN	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
1	1	-	1	PTE0	DISABLED		PTE0		UART1_TX	RTC_ CLKOUT	CMP0_OUT	I2C1_SDA	
2	2	—	2	PTE1	DISABLED		PTE1	SPI1_MOSI	UART1_RX		SPI1_MISO	I2C1_SCL	
3	_	-	-	PTE2	DISABLED		PTE2	SPI1_SCK					
4	_	-	-	PTE3	DISABLED		PTE3	SPI1_MISO			SPI1_MOSI		
5	_	-	-	PTE4	DISABLED		PTE4	SPI1_PCS0					



80 LQFP	64 LQFP	48 QFN	32 QFN	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
6	_	_	_	PTE5	DISABLED		PTE5						
7	3	1	_	VDD	VDD	VDD							
8	4	2	_	VSS	VSS	VSS							
9	5	3	3	PTE16	ADC0_SE1	ADC0_SE1	PTE16	SPI0_PCS0	UART2_TX	TPM_ CLKIN0			
10	6	4	4	PTE17	ADC0_SE5a	ADC0_SE5a	PTE17	SPI0_SCK	UART2_RX	TPM_ CLKIN1		LPTMR0_ ALT3	
11	7	5	5	PTE18	ADC0_SE2	ADC0_SE2	PTE18	SPI0_MOSI		I2C0_SDA	SPI0_MISO		
12	8	6	6	PTE19	ADC0_SE6a	ADC0_SE6a	PTE19	SPI0_MISO		I2C0_SCL	SPI0_MOSI		
13	9	7	-	PTE20	ADC0_SE0	ADC0_SE0	PTE20		TPM1_CH0	UART0_TX			
14	10	8	-	PTE21	ADC0_SE4a	ADC0_SE4a	PTE21		TPM1_CH1	UART0_RX			
15	11	Ι	-	PTE22	ADC0_SE3	ADC0_SE3	PTE22		TPM2_CH0	UART2_TX			
16	12	Ι	-	PTE23	ADC0_SE7a	ADC0_SE7a	PTE23		TPM2_CH1	UART2_RX			
17	13	9	7	VDDA	VDDA	VDDA							
18	14	10	-	VREFH	VREFH	VREFH							
19	15	11	_	VREFL	VREFL	VREFL							
20	16	12	8	VSSA	VSSA	VSSA							
21	17	13	_	PTE29	CMP0_IN5/ ADC0_SE4b	CMP0_IN5/ ADC0_SE4b	PTE29		TPM0_CH2	TPM_ CLKIN0			
22	18	14	9	PTE30	ADC0_SE23/ CMP0_IN4	ADC0_SE23/ CMP0_IN4	PTE30		TPM0_CH3	TPM_ CLKIN1			
23	19	—	_	PTE31	DISABLED		PTE31		TPM0_CH4				
24	20	15	—	PTE24	DISABLED		PTE24		TPM0_CH0		I2C0_SCL		
25	21	16	_	PTE25	DISABLED		PTE25		TPM0_CH1		I2C0_SDA		
26	22	17	10	PTA0	SWD_CLK		PTA0		TPM0_CH5				SWD_CLK
27	23	18	11	PTA1	DISABLED		PTA1	UART0_RX	TPM2_CH0				
28	24	19	12	PTA2	DISABLED		PTA2	UART0_TX	TPM2_CH1				
29	25	20	13	PTA3	SWD_DIO		PTA3	I2C1_SCL	TPM0_CH0				SWD_DIO
30	26	21	14	PTA4	NMI_b		PTA4	I2C1_SDA	TPM0_CH1				NMI_b
31	27	Ι	-	PTA5	DISABLED		PTA5		TPM0_CH2				
32	28	Ι	-	PTA12	DISABLED		PTA12		TPM1_CH0				
33	29	-	-	PTA13	DISABLED		PTA13		TPM1_CH1				
34	_	_	_	PTA14	DISABLED		PTA14	SPI0_PCS0	UART0_TX				
35	_	-	_	PTA15	DISABLED		PTA15	SPI0_SCK	UART0_RX				
36	_	-	_	PTA16	DISABLED		PTA16	SPI0_MOSI			SPI0_MISO		
37	-	-	-	PTA17	DISABLED		PTA17	SPI0_MISO			SPI0_MOSI		
38	30	22	15	VDD	VDD	VDD							
39	31	23	16	VSS	VSS	VSS							
40	32	24	17	PTA18	EXTAL0	EXTAL0	PTA18		UART1_RX	TPM_ Clkino			





Figure 16. KL14 80-pin LQFP pinout diagram





Figure 17. KL14 64-pin LQFP pinout diagram





Figure 18. KL14 48-pin QFN pinout diagram



Revision history



8.9 Typical value conditions

Typical values assume you meet the following conditions (or other conditions as specified):

 Table 34.
 Typical value conditions

Symbol	Description	Value	Unit
T _A	Ambient temperature	25	۵°C
V _{DD}	3.3 V supply voltage	3.3	V

9 Revision history

The following table provides a revision history for this document.

Rev. No.	Date	Substantial Changes	
2	9/2012	Completed all the TBDs, initial public release.	
3	9/2012	Updated Signal Multiplexing and Pin Assignments table to add UART2 signals.	
4	3/2014	Updated the front page and restructured the chapters	
Table continues on the next page			

Table 35. Revision history

Rev. No.	Date	Substantial Changes	
		 Added a note to the I_{LAT} in the ESD handling ratings Updated Voltage and current operating ratings Updated Voltage and current operating requirements Updated the Voltage and current operating behaviors Updated Power mode transition operating behaviors Updated Capacitance attributes Updated footnote in the Device clock specifications Updated Voltage and voltage and voltage and added a note to them in the 12-bit ADC operating conditions Updated Temp sensor slope and voltage and added a note to them in the 12-bit ADC operating requirements Added Inter-Integrated Circuit Interface (I2C) timing 	
5	08/2014	 Updated related source and added block diagram in the front page Updated Power consumption operating behaviors 	





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